

Polar3™ HiPerFET™ **Power MOSFET**

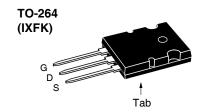
IXFK120N30P3 IXFX120N30

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode



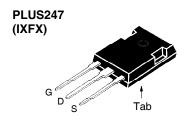
	_ D33		
P3	I _{D25}	=	120A
	R _{DS(on)}	≤	$27m\Omega$
O D	t _{rr}	≤	250ns

 $V_{\rm DSS}$



300V

Symbol	Test Conditions	Maximum F	Ratings
V _{DSS}	$T_J = 25$ °C to 150°C	300	V
V _{DGR}	$T_J = 25$ °C to 150°C, $R_{GS} = 1M\Omega$	300	
V _{GSS}	Continuous	± 20	V
V _{GSM}	Transient	± 30	
I _{D25}	$T_{\rm C} = 25^{\circ}{\rm C}$	120	A
	$T_{\rm C} = 25^{\circ}{\rm C}$, Pulse Width Limited by $T_{\rm JM}$	300	A
I _A	$T_c = 25$ °C	60	A
E _{AS}	$T_c = 25$ °C	3	J
$\overline{\mathbf{P}_{_{\mathrm{D}}}}$	T _c = 25°C	1130	W
dv/dt	$I_{\text{S}} \leq I_{\text{DM}}, V_{\text{DD}} \leq V_{\text{DSS}}, T_{\text{J}} \leq 150^{\circ}\text{C}$	35	V/ns
T _J T _{JM} T _{stg}		-55 +150 150 -55 +150	0° 0°
T _L T _{SOLD}	Maximum Lead Temperature for Soldering	300	°C
	Plastic Body for 10s	260	°C
M _d	Mounting Torque (TO-264)	1.13/10	Nm/lb.in
F _c	Mounting Force (PLUS247)	20120 /4.527	N/lb
Weight	TO-264	10	g
	PLUS247	6	g



G	=	Gate	D	=	=	Drain
S	=	Source	Τá	ab =	=	Drain

Features

- Dynamic dv/dt Rating
- Avalanche Rated
- Fast Intrinsic Diode
- Low Q_G
- Low R_{DS(on)}
 Low Drain-to-Tab Capacitance
- Low Package Inductance

Advantages

- · Easy to Mount
- Space Savings

Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode **Power Supplies**
- Uninterrupted Power Supplies
- AC Motor Drives
- High Speed Power Switching Applications

Symbol Test Conditions Chara (T ₁ = 25°C Unless Otherwise Specified) Min.		acteristic Values Typ. Max.			
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BV _{DSS}	$V_{GS} = 0V, I_D = 1mA$	300			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 4mA$	3.0		5.0	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 200	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$			25	μΑ
	$T_J = 125$	5°C		750	μΑ
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			27	mΩ



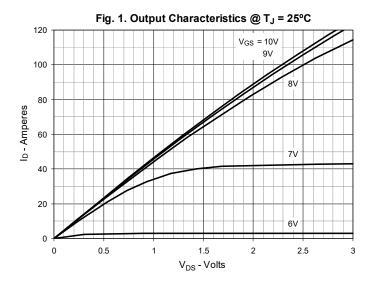
Symbol	Test Conditions	Chara	cteristic \	/alues
$(T_J = 25^\circ)$	C Unless Otherwise Specified)	Min.	Тур.	Max.
\mathbf{g}_{fs}	$V_{DS} = 10V, I_{D} = 0.5 \bullet I_{D25}, No.$	te 1 54	90	s
C _{iss}			8630	pF
\mathbf{C}_{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1M$	Hz	1406	pF
C _{rss}	J		20	pF
R _{Gi}	Gate Input Resistance		1.5	Ω
t _{d(on)}	Resistive Switching Times	3	26	ns
t _r	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS},$		13	ns
$\mathbf{t}_{d(off)}$	$R_{G} = 1\Omega \text{ (External)}$	1 _D = 0.0 1 _{D25}	60	ns
t _f) Ti _G = 122 (External)		11	ns
$\mathbf{Q}_{g(on)}$			150	nC
\mathbf{Q}_{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \bullet V_{DSS},$	$I_{D} = 0.5 \bullet I_{D25}$	40	nC
\mathbf{Q}_{gd}	J		53	nC
R _{thJC}				0.11 °C/W
R _{thCS}			0.15	°C/W

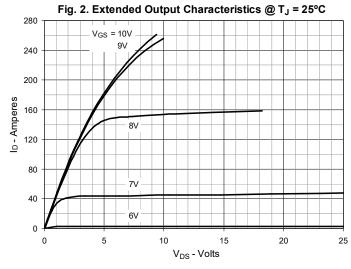
Source-Drain Diode

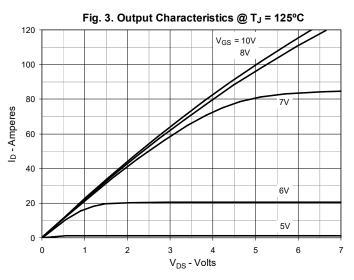
Symbol Test Conditions		Chai	Characteristic Values			
$(T_J = 2)$	25°C, Unless Otherwise Specified)	Min.	Тур.	Max.		
Is	$V_{GS} = 0V$			120	Α	
I _{sm}	Repetitive, Pulse Width Limited by T_{JM}			480	Α	
V _{sD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V	
t _{rr}	$I_{\rm E} = 60A$, -di/dt = 100A/ μ s			250	ns	
$\mathbf{Q}_{_{\mathbf{RM}}}$	> '		2.2		μC	
I _{RM}	$\int V_{R} = 100V, V_{GS} = 0V$		19.6		Α	

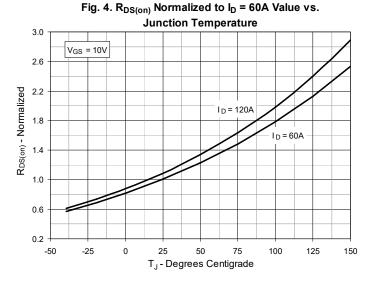
Note 1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$.

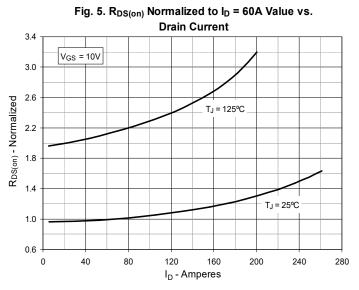


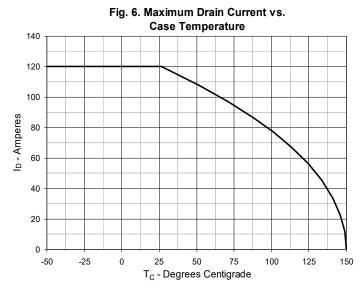




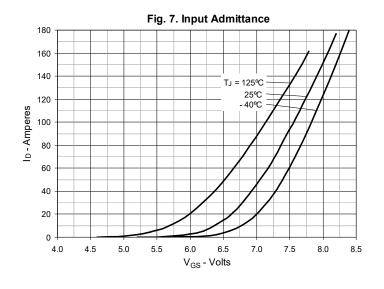


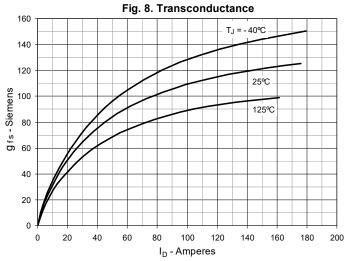


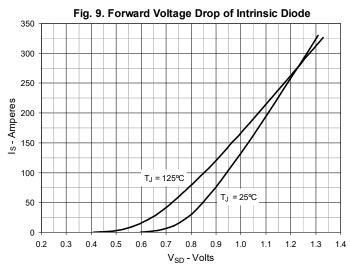


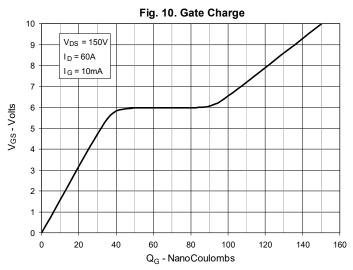


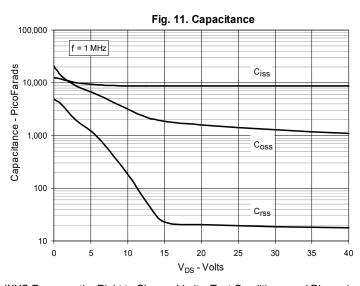


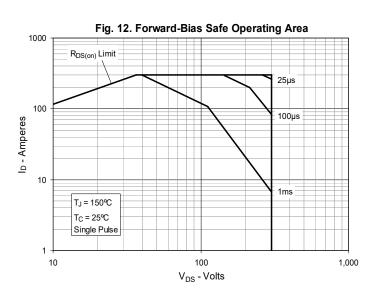






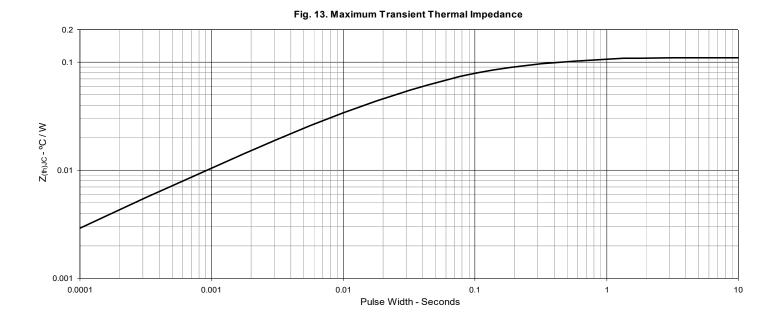






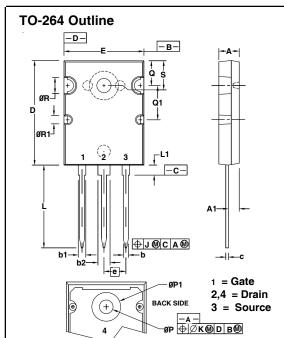
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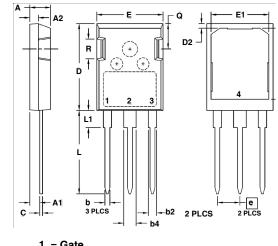
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CVMDOL	SYMBOL INCHES		MILLIM	ETERS
SIMBOL	MIN	MAX	MIN	MAX
Α	.185	.209	4.70	5.31
A1	.102	.118	2.59	3.00
b	.037	.055	0.94	1.40
b1	.087	.102	2.21	2.59
b2	.110	.126	2.79	3.20
С	.017	.029	0.43	0.74
D	1.007	1.047	25.58	26.59
E	.760	.799	19.30	20.29
е	.215BSC		5.46 BSC	
J	.000	.010	0.00	0.25
K	.000	.010	0.00	0.25
L	.779	.842	19.79	21.39
L1	.087	.102	2.21	2.59
ØΡ	.122	.138	3.10	3.51
Ø₽1	.270	.290	6.86	7.37
Q	.240	.256	6.10	6.50
Q1	.330	.346	8.38	8.79
ØR	.155	.187	3.94	4.75
ØR1	.085	.093	2.16	2.36
S	.243	.253	6.17	6.43

PLUS247™ Outline



1 = Gate
2,4 = Drain
3 = Source

SYM	INCHES		MILLIMETERS	
2110	MIN	MAX	MIN	MAX
Α	.190	.205	4.83	5.21
Α1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2,16
b	.045	.055	1.14	1,40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3,20
С	.024	،031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
E	.620	.635	15.75	16.13
E1	.520	.560	13,08	14.22
е	.215	BSC	5,45 BSC	
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
Q	.220	.244	5.59	6.20
R	.170	190،	4.32	4.83





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